TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74AC157P, TC74AC157F, TC74AC157FN, TC74AC157FT

QUAD 2 - CHANNEL MULTIPLEXER

The TC74AC157 is an advanced high speed CMOS QUAD 2-CHANNEL MULTIPLEXER fabricated with silicon gate and double-layer metal wiring C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device consist of four 2-input digital multiplexer with common select and strobe inputs.

When the STROBE input is held "H" level, selection of data is inhibited and all the outputs become "L" level.

The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES:

- High Speed······ t_{pd} = 4.5ns(typ.) at V_{CC} = 5V
- Low Power Dissipation ······· $I_{CC} = 8\mu A(Max.)$ at $Ta = 25^{\circ}C$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Symmetrical Output Impedance··· $|I_{OH}| = I_{OL} = 24$ mA(Min.)

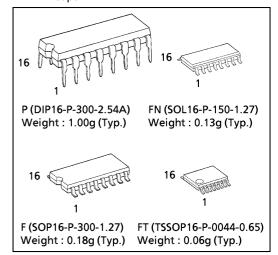
 Capability of driving 50Ω

transmission lines.

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- Balanced Propagation Delays $\cdots t_{pLH} \simeq t_{pHL}$
- Wide Operating Voltage Range ···· V_{CC} (opr) = 2V ~ 5.5V
- Pin and Function Compatible with 74F157

(Note) The JEDEC SOP (FN) is not available in Japan.



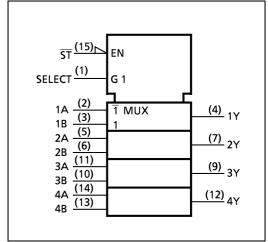
PIN ASSIGNMENT SELECT 1 16 V_{CC} 2 ASG 15 ST 3 В 14 **4**A 1B 4 В 13 4B 5 12 4Y 2Α Α 6 В Α 11 10 7 3B 2Y GND 8 9 (TOP VIEW)

TRUTH TABLE

	OUTPUTS			
ST	SELECT	Α	В	Υ
Н	Х	Х	Х	L
L	L	L	Х	L
L	L	Н	Х	Н
L	Н	Х	L	L
L	Н	Х	Н	Н

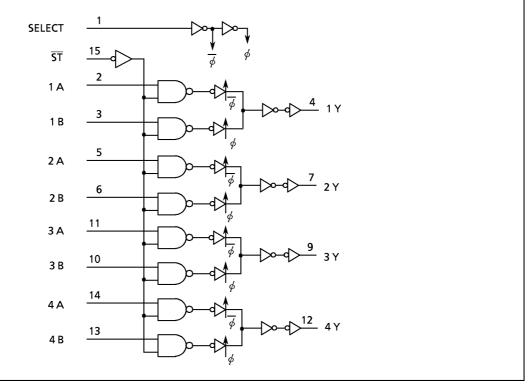
X : Don't Care

IEC LOGIC SYMBOL



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SYSTEM DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	V
DC Input Voltage	V _{IN}	$-0.5 \sim V_{CC} + 0.5$	٧
DC Output Voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I _{IK}	± 20	mA
Output Diode Current	I _{OK}	± 50	mA
DC Output Current	I _{OUT}	± 50	mA
DC V _{CC} /Ground Current	I _{cc}	± 100	mΑ
Power Dissipation	P _D	500 (DIP)*/180 (SOP/TSSOP)	mW
Storage Temperature	T _{stg}	−65~150	°C

*500mW in the range of Ta = -40° C ~65°C. From Ta = 65°C to 85°C a derating factor of -10mW/°C should be applied up to 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2.0~5.5	٧
Input Voltage	V _{IN}	0~V _{CC}	٧
Output Voltage	V _{OUT}	0~V _{CC}	٧
Operating Temperature	T _{opr}	−40~85	°C
Input Rise and Fall Time	dt/dV	$0 \sim 100 \text{ (Vcc} = 3.3 \pm 0.3 \text{V)}$ $0 \sim 20 \text{ (Vcc} = 5 \pm 0.5 \text{V)}$	ns / V

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DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V _{cc}	Ta = 25°C			Ta = −40~85°C		UNIT
FANAIVIETEN STIVIBUI		TEST CONDITION		(5)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
High - Level Input Voltage	V _{IH}		2.0 3.0 5.5	1.50 2.10 3.85	1 1 1	_ _ _	1.50 2.10 3.85		V	
Low - Level Input Voltage	VIL		2.0 3.0 5.5	111	111	0.50 0.90 1.65	_ _ _	0.50 0.90 1.65	٧	
High - Level Output Voltage	V _{OH}	V _{I N} =	$I_{OH} = -50\mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	_ _ _	1.9 2.9 4.4	_ _ _	.,
		V _{IH} or V _{IL}	$I_{OH} = -4mA$ $I_{OH} = -24mA$ $I_{OH} = -75mA*$	3.0 4.5 5.5	2.58 3.94 —		_ _ _	2.48 3.80 3.85	 - -	٧
Low - Level	V	V _{I N} =	$I_{OL} = 50 \mu A$	2.0 3.0 4.5	111	0.0 0.0 0.0	0.1 0.1 0.1	_ _ _	0.1 0.1 0.1	>
Output Voltage	V _{OL} V _{IH} or V _{IL}	$I_{OL} = 12\text{mA}$ $I_{OL} = 24\text{mA}$ $I_{OL} = 75\text{mA*}$	3.0 4.5 5.5	111	111	0.36 0.36 —	_ _ _	0.44 0.44 1.65	V	
Input Leakage Current	I _{IN}	$V_{IN} = V_{CC}$ or GND		5.5			±0.1	_	± 1.0	
Quiescent Supply Current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_		8.0	_	80.0	μA

^{* :} This spec indicates the capability of driving 50Ω transmission lines. One output should be tested at a time for a 10ms maximum duration.

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 pF$, $R_L = 500 \Omega$, Input $t_r = t_f = 3 ns$)

PARAMETER	SYMBOL	TEST CONDITION		•	Ta = 25°C	-	$Ta = -40 \sim 85^{\circ}C$		UNIT
PARAIVIETER	STIVIBOL		V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	OINII
Propagation Delay Time $(A, B-Y)$	t _{pLH} t _{pHL}		3.3 ± 0.3 5.0 ± 0.5		7.2 5.5	12.2 7.9	1.0 1.0	14.0 9.1	
Propagation Delay Time (SELECT—Y)	t _{pLH} t _{pHL}		3.3 ± 0.3 5.0 ± 0.5		8.5 6.3	14.5 9.1	1.0 1.0	16.7 10.5	ns
Propagation Delay Time $(\overline{ST} - Y)$	t _{pLH} t _{pHL}		3.3 ± 0.3 5.0 ± 0.5		8.6 6.4	14.6 9.2	1.0 1.0	16.8 10.6	
Input Capacitance	C _{IN}			_	5	10	_	10	ne
Power Dissipation Capacitance	C _{PD} (1)			_	93	_	_	_	pF

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

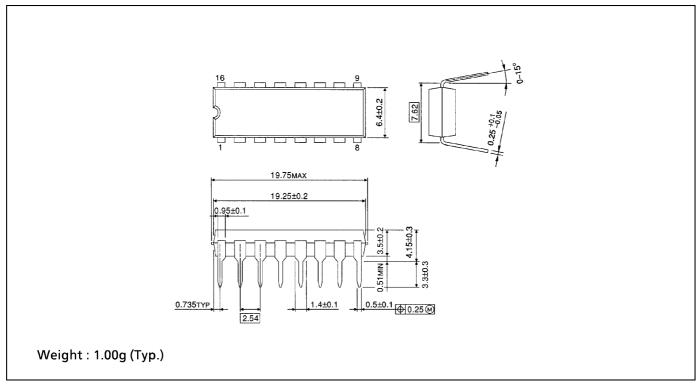
Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr.) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 4$ (per bit)

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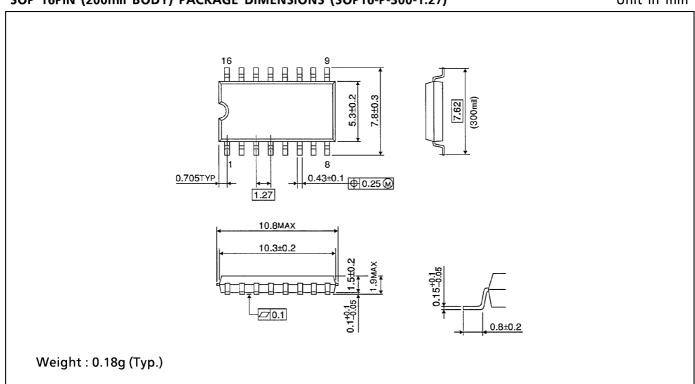
DIP 16PIN PACKAGE DIMENSIONS (DIP16-P-300-2.54A)

Unit in mm



SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

Unit in mm

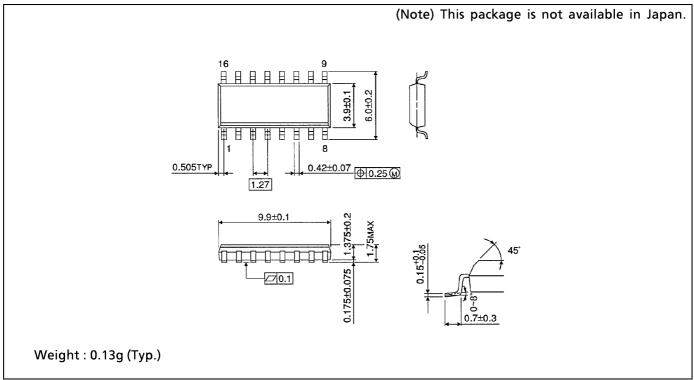


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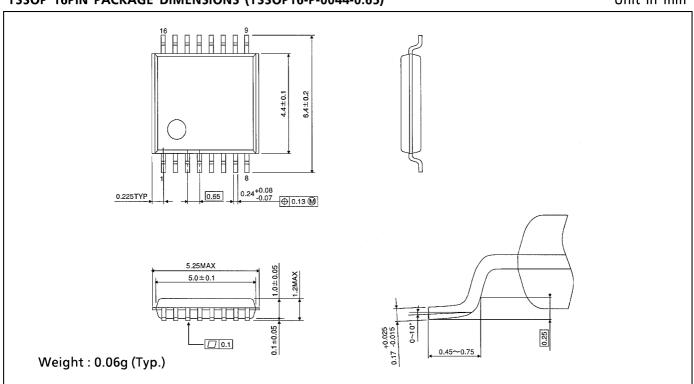
SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150 -1.27)

Unit in mm



TSSOP 16PIN PACKAGE DIMENSIONS (TSSOP16-P-0044-0.65)

Unit in mm



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